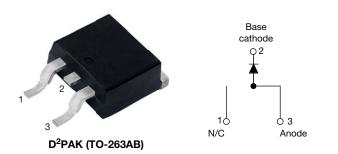
**Vishay Semiconductors** 

# **High Performance Schottky Rectifier, 20 A**



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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub> 20 A					
V <sub>R</sub>	15 V				
V <sub>F</sub> at I <sub>F</sub>	0.33 V				
I <sub>RM</sub> max.	600 mA at 100 °C				
T <sub>J</sub> max.	125 °C				
E <sub>AS</sub>	10 mJ				
Package	D <sup>2</sup> PAK (TO-263AB)				
Circuit configuration	Single				

### **FEATURES**

- 125 °C T<sub>J</sub> operation (V<sub>B</sub> < 5 V)</li>
- · Single diode configuration
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- · Guard ring for enhanced ruggedness and long term reliability
- · High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	. CHARACTERISTICS VALUES UNITS							
I <sub>F(AV)</sub>	Rectangular waveform	20	А					
V <sub>RRM</sub>		15	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	700	А					
V <sub>F</sub>	19 $A_{pk}$ , $T_J$ = 125 °C (typical)	0.25	V					
TJ	Range	-55 to +125	C°					

VOLTAGE RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20L15TS-M3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	T <sub>1</sub> = 100 °C	15	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	1j = 100 C	15	v		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 85 °C, re	20					
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	700	А			
See fig. 7		10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	330				
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 6 mH		10	mJ			
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		2	А			

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS	
Forward voltage drop See fig. 1		19 A	T <sub>1</sub> = 25 °C	-	0.41		
	V <sub>FM</sub> <sup>(1)</sup>	40 A	1j=25 0	-	0.52	v	
	VFM (''	19 A	T <sub>1</sub> = 125 °C	0.25	0.33	v	
		40 A	1j=125 0	0.37	0.50	1	
Reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	-	10	mA	
See fig. 2	IRM \''	$T_J = 100 \ ^\circ C$	V <sub>R</sub> = naleu V <sub>R</sub>	-	600		
Threshold voltage	V <sub>F(TO)</sub>	(TO) T T movimum 0.182		82	V		
Forward slope resistance	r <sub>t</sub>	ij = ij maximum	$T_J = T_J$ maximum				
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ , (test signal ran	-	2000	pF		
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 m	-	nH			
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000				V/µs	

Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	TJ		-55 to +125	°C		
Maximum storage temperature range	T <sub>Stg</sub>		-55 to +150	– °C		
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	1.5			
Typical thermal resistance, case to heatsink R <sub>thCS</sub>		Mounting surface, smooth and greased (For TO-220)	0.50	°C/W		
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	R <sub>thJA</sub> DC operation				
Approximate weight			2	g		
Approximate weight			0.07	oz.		
Mounting torgue		Non-lubricated threads	6 (5)	kgf ⋅ cm		
Mounting torque maximum			12 (10)	(lbf · in)		
Marking device		Case style D <sup>2</sup> PAK (TO-263AB) 20L15TS		5TS		

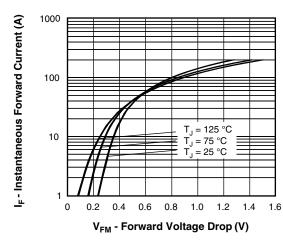


Fig. 1 - Maximum Forward Voltage Drop Characteristics

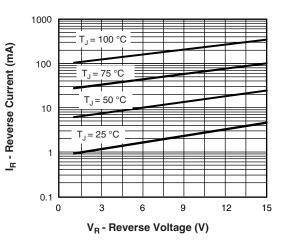


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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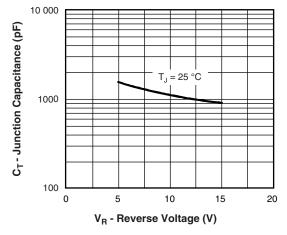


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

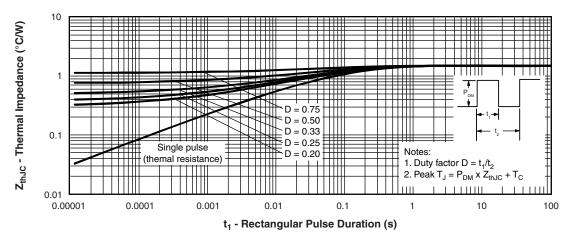
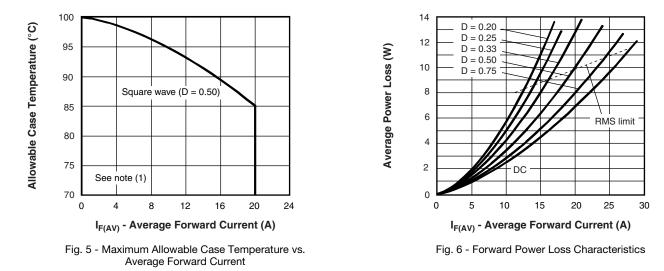


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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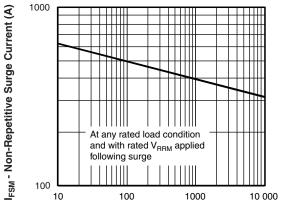
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# VS-20L15TS-M3

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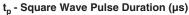


Fig. 7 - Maximum Non-Repetitive Surge Current

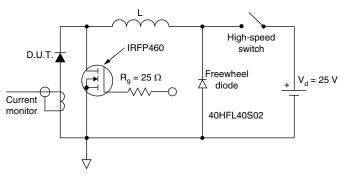
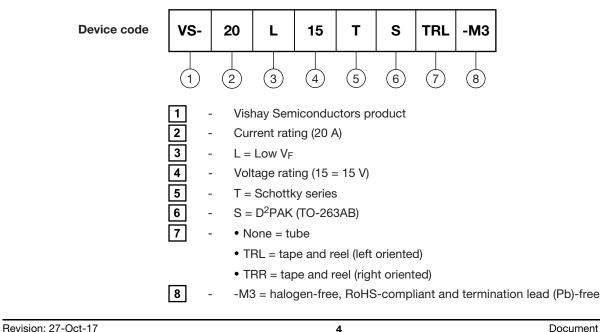


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

#### **ORDERING INFORMATION TABLE**



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## Vishay Semiconductors

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-20L15TS-M3	50	1000	Antistatic plastic tubes					
VS-20L15TSTRL-M3	800	800	13" diameter reel					
VS-20L15TSTRR-M3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96424				

# **Outline Dimensions**



D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches

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SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

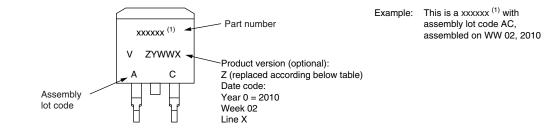
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D<sup>2</sup>PAK



#### Note

<sup>(1)</sup> If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION			
A	Termination lead (Pb)-free			
В	Totally lead (Pb)-free			
E	RoHS-compliant and termination lead (Pb)-free			
F	RoHS-compliant and totally lead (Pb)-free			
М	Halogen-free, RoHS-compliant, and termination lead (Pb)-free			
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free			
G	Green			



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